VSLY5850



Vishay Semiconductors

High Speed Infrared Emitting Diode, 850 nm, Surface Emitter Technology



DESCRIPTION

As part of the <u>SurfLightTM</u> portfolio, the VSLY5850 is an infrared, 850 nm emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensity, high optical power and high speed, molded in a clear, untinted plastic package, with a parabolic lens.

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Leads with stand-off
- Peak wavelength: $\lambda_p = 850 \text{ nm}$
- High reliability
- High radiant power
- High radiant intensity
- Narrow angle of half intensity: $\varphi = \pm 3^{\circ}$
- · Suitable for high pulse current operation
- · Good spectral matching with CMOS cameras
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- Smoke-automatic fire detectors
- IR Flash

PRODUCT SUMMARY COMPONENT I_e (mW/sr) φ (°) λ_p (nm) t_r (ns) VSLY5850 600 ± 3 850 10

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
VSLY5850	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾				

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V _R	5	V		
Forward current		١ _F	100	mA		
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA		
Surge forward current	t _p = 100 μs	I _{FSM}	1	A		
Power dissipation		Pv	190	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	- 40 to + 85	°C		
Storage temperature range		T _{stg}	- 40 to + 100	°C		
Soldering temperature	$t \leq 5 \; \text{s}, 2 \; \text{mm}$ from case	T _{sd}	260	°C		
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W		

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1 For technical questions, contact: <u>sensorstechsupport@vishay.com</u> Document Number: 83160







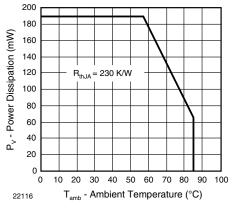


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

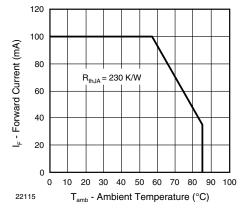


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.65	1.9	V	
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.9		V	
Temperature coefficient of V_{F}	I _F = 1 mA	TK _{VF}		- 1.45		mV/K	
	I _F = 10 mA	TK _{VF}		- 1.25		mV/K	
Reverse current		I _R	not designed for reverse operation			μA	
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		125		pF	
Radiant intensity	I _F = 100 mA, t _p = 20 ms	l _e	300	600	900	mW/sr	
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e		5100		mW/sr	
Radiant power	I _F = 100 mA, t _p = 20 ms	фе		55		mW	
Temperature coefficient of ϕ_{e}	I _F = 100 mA	ΤKφ _e		- 0.35		%/K	
Angle of half intensity		φ		± 3		0	
Peak wavelength	I _F = 100 mA	λρ	840	850	870	nm	
Spectral bandwidth	I _F = 100 mA	Δλ		30		nm	
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλρ		0.25		nm/K	
Rise time	I _F = 100 mA	t _r		10		ns	
Fall time	I _F = 100 mA	t _f		10		ns	



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

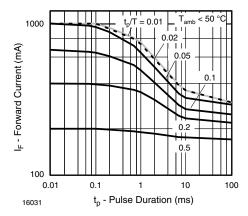


Fig. 3 - Pulse Forward Current vs. Pulse Duration

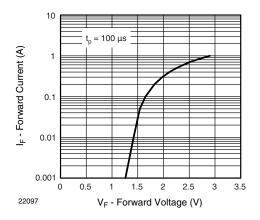


Fig. 4 - Forward Current vs. Forward Voltage

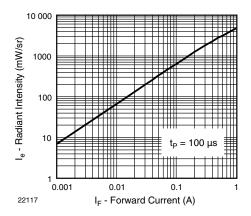


Fig. 5 - Radiant Intensity vs. Forward Current

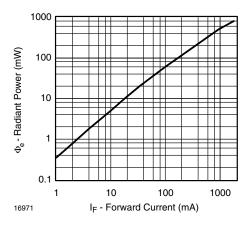


Fig. 6 - Radiant Power vs. Forward Current

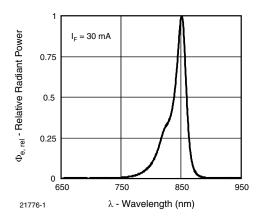


Fig. 7 - Relative Radiant Power vs. Wavelength

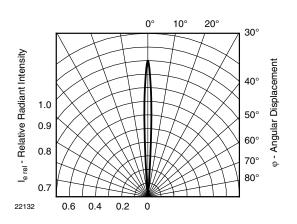


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

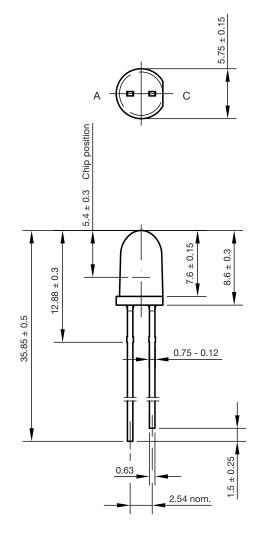
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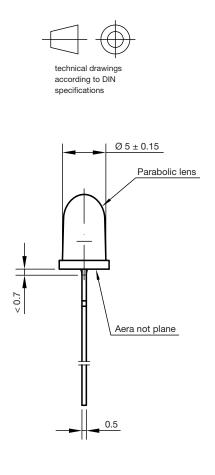


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PACKAGE DIMENSIONS in millimeters







Not indicated tolerances ± 0.1



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